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Lattice disorder influences the photocarrier dynamics in lead halide perovskites†

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Revealing the structural impact of lead halide perovskites on photocarrier dynamics is essential for the associated solar cells but deficient in experimental visualization. In this study, with femtosecond spectroscopy, we for the first time explored the contribution of the disorder of the distorted PbX_6 octahedrons and A-site cations on the carrier behaviours. It was found that photoinduced carriers recombine almost twice slower and diffuse 20% faster in the disordered, β -phased samples than in the ordered, γ -phased ones. Yet within the same phase, with a similar PbX_6 orientation but various A-site mobility, the carrier diffusion and recombination have no apparent difference. Thus we firmly conclude that lattice disorder effectively influences the carrier dynamics and therein the Pb–X sublattice is worth more than A-site cations, which should inspire future lead halide perovskite design and applications.

Introduction

Lead halide perovskites (LHPs) with a general chemical formula APbX_3 [$\text{A} = \text{CH}_3\text{NH}_3^+$ (MA^+), $\text{CH}(\text{NH}_2)_2^+$ (FA^+), Cs^+ ; $\text{X} = \text{I}^-$, Br^- , Cl^-] have been demonstrated as one of the most attractive candidates for various optoelectronic applications, especially for the next-generation solar cells.^{1,2} Owing to the combination of low-cost fabrication and outstanding photoelectric properties including high carrier mobility and high defect tolerance, the power conversion efficiency of perovskite solar cells has soared from the initial unstable 3.8%³ to the certified 25.7%.⁴ Some latest device studies have suggested that the record high

New concepts

Using femtosecond spectroscopy, we monitored photocarrier dynamics in β -phase CsPbI_3 , MAPbI_3 , $\text{FA}_{0.9}\text{Cs}_{0.1}\text{PbI}_3$ and γ -phase MAPbI_3 and CsPbI_3 perovskites. We found that photoinduced carriers recombine almost two times slower and diffuse 20% faster in the disordered, β -phase samples than in the ordered, γ -phase ones. Yet within the same phase, with a similar PbX_6 orientation but various A-site mobility, the carrier diffusion and recombination have no apparent difference. These results indicate that lattice disorder is the main factor that influences the carrier dynamics and therein the Pb–X sublattice is worth more than A-site cations.

efficiency is contributed by the lattice strain management of LHPs through suppressing defects and reducing carrier recombination.^{5–7} The lattice structure (phase)^{1,8} of LHPs is determined by the distortion and orientation ordering of PbX_6 octahedrons and A-site cations (Table 1).^{9–17} To further improve the efficiency, it is extremely important to reveal the relationship between the structure and the underlying physical mechanisms, such as carrier dynamics in the perovskite absorber layer. Although the important influence of both the PbX_6 octahedron and A-site cation has been predicted theoretically,^{9–16} their contribution to carrier recombination and diffusion is still unclear limited by the lack of direct experimental evidence.

In this work, using the ultrafast transient reflectance (TR) technique we explored the influence of the distorted PbX_6 octahedrons by tracing the photocarrier dynamics in β - and γ -phased perovskites with disorderly and orderly Pb–I sublattices, respectively. The effect of the A-site cations is revealed as well

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Table 1 Relationship of structure with distortion and orientation

Structure/phase	PbX_6 distortion	PbX_6 orientation	A-site orientation organic/inorganic
Cubic/ α	Undistorted	Disorder	Disorder/order
Tetragonal/ β	Randomly distorted	Disorder	Disorder/order
Orthorhombic/ γ	Harmonically distorted	Order	Order/order

by the photocarrier dynamics in the same phase, *i.e.* either β -phased (MAPbI_3 , $\text{FA}_{0.9}\text{Cs}_{0.1}\text{PbI}_3$ and CsPbI_3),^{18–21} or γ -phased (MAPbI_3 and CsPbI_3) perovskites, which have a similar distorted Pb–I sublattice, but a different A-site component. We found that the photoinduced carriers recombined almost 2 times slower and diffused 20% faster in the β -phased samples than in the γ -phased ones, while within the β - or γ -phased siblings, the carrier diffusion and recombination rates have no obvious difference. Since the crystal phase is majorly determined by the distortion property of the PbX_6 octahedrons and then modified by the mobility of the A-site cations, we firmly conclude that the Pb–X sublattice is worth more than A-site cations in the carrier dynamics of LHPs. Considering that both are kinds of strain relaxation,¹⁷ our results provide a new perspective on the effect of strain management, *i.e.* assisting carrier diffusion and retarding electron–hole recombination, besides suppressing defects.^{5,6}

Experiments and data analysis

The recently established preparation methods for the room-temperature thermodynamically stable β -²² and γ -²³ phased CsPbI_3 films form the prerequisites of this work. Following them and the standard fabrication procedures for the β -phased MAPbI_3 ^{24,25} and $\text{FA}_{0.9}\text{Cs}_{0.1}\text{PbI}_3$,²⁶ we obtained all room-temperature stable films using a single-step spin-coating method with a thickness of about 200 nm. It should be noted that normally at room temperature FAPbI_3 is in the cubic α phase and in order to realize a β -phased perovskite with FA^+ dominated A-site cations, a partial substitution of FA^+ with Cs^+ was induced as $\text{FA}_{0.9}\text{Cs}_{0.1}\text{PbI}_3$.^{26–28} The crystalline quality of all samples was well-recognized at room temperature with full characterizations (for more details, see S1, ESI†). As has been proved by many experimental studies, the crystal structure of MAPbI_3 can be controlled by temperature.^{1,29,30} At room temperature, the MAPbI_3 film is in the β phase, and the γ -phased MAPbI_3 applied in the TR measurement was realized by cooling the sample to 100 K using a temperature-controlled cryostat.

The bandgaps of the β - CsPbI_3 , γ - CsPbI_3 , β - MAPbI_3 and β - $\text{FA}_{0.9}\text{Cs}_{0.1}\text{PbI}_3$ films were determined by the absorption spectra shown in Fig. S1(b) (ESI†) to be 1.68, 1.73, 1.58 and 1.55 eV, respectively. Thus, in TR measurements, 395 nm (3.14 eV) and 790 nm (1.57 eV) were selected as the pump and probe light, respectively. The former would excite electrons from the valence band to the conduction band and modulate the reflectance of the perovskites, R . The latter is very sensitive to such change since its photon energy is close to the bandgaps and its real time relative reflectance change $-\Delta R_t/R$ was recorded as a reflection of excited carrier density n_t at any delay time t (the TR experimental setup is detailed in S2, ESI†).

The carrier dynamics are presented by $-\Delta R_t/R$ in Fig. 1(a) and (b) and Fig. S2(a)–(c) (ESI†) for β - CsPbI_3 , γ - CsPbI_3 , β - MAPbI_3 , γ - MAPbI_3 and β - $\text{FA}_{0.9}\text{Cs}_{0.1}\text{PbI}_3$ films, respectively. All TR traces exhibit a sharp increase initially (<1 ps) to the maximum reflectivity change $(-\Delta R_t/R)_{\text{max}}$ and then a slow

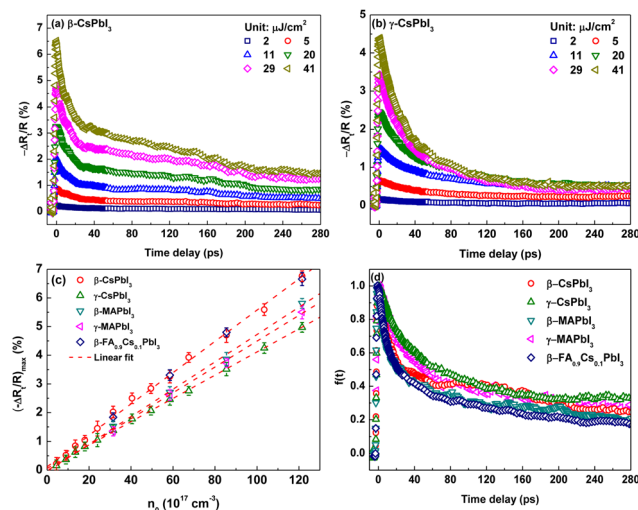


Fig. 1 (a and b) The pump fluence dependent TR kinetics for β - and γ - CsPbI_3 , respectively; (c) plots of $(-\Delta R_t/R)_{\text{max}}$ as a function of initial excited carrier density; (d) the recovery function for five perovskite films at a pump fluence of 11 $\mu\text{J cm}^{-2}$.

recovery (tens to hundreds of picoseconds). The former is typically assigned to the photoinduced electron/hole assemblage in the conduction/valence bands right after the 3.14 eV photoexcitation.^{31,32} The initial assembled photocarrier density n_0 can be calculated as $n_0 = \alpha(F/3.14 \text{ eV})$,³¹ where F is the pump fluence and α is the sample absorption coefficient at the 395 nm pump wavelength ($\alpha \sim 1.5 \times 10^5 \text{ cm}^{-1}$ for all samples^{33–36}). As shown in Fig. 1(c), $(-\Delta R_t/R)_{\text{max}}$ linearly depends on n_0 for all samples, which leads to the connection as $(-\Delta R_t/R)_{\text{max}} = bn_0$ with a positive linear coefficient b . In the following we assume that $-\Delta R_t/R$ and n_t share the same recovery function $f(t)$ as $-\Delta R_t/R = (-\Delta R_t/R)_{\text{max}}f(t) = bn_0f(t) = bn_t$. Therefore, the slow recovery is actually the depopulation process of the excited carrier in the probed volume, as discussed below through diffusion and electron–hole recombination. The normalized TR traces, essentially $f(t)$, shown in Fig. 1(d) hint that from the perspective of carrier dynamics, these five samples could be roughly divided into two clusters, which is in agreement with the structure phase, *i.e.* samples with the same phase have similar carrier behaviour, especially in the first 40 ps.

In LHPs, the photocarrier depopulation is usually described by the rate equation³¹ $-dn_t/dt = k_1n_t + k_2n_t^2 + k_3n_t^3$, in which the three terms on the right hand side are successively ascribed to: (1) a first-order Shockley–Reed (trap state-mediated) recombination or carrier diffusion out of the probing region; (2) a second-order non-geminate/free carrier recombination; and (3) a three-body Auger recombination,³² with k_1 , k_2 and k_3 being the corresponding depopulation rate constants, respectively. Owing to the low pump fluence ($2\text{--}42 \mu\text{J cm}^{-2}$) used in this work, Auger recombination could be neglected. Further analysis confirms that the carrier dynamics are mainly dominated by the first and second order mechanisms (detailed in S3, ESI†) and as a result the rate equation is simplified as $-dn_t/dt = k_1n_t +$

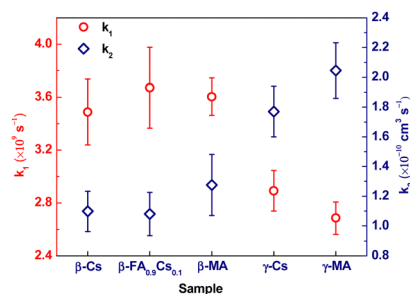


Fig. 2 Diffusion rate constant k_1 and electron–hole recombination rate constant k_2 for various APbI₃ films with their phase and A-site cation listed at the horizontal axis.

$k_2 n_t^2$ with its analytic solution $n_t = k_1 n_0 / [(k_2 n_0 + k_1) e^{k_1 t} - k_2 n_0]$. Thus, the TR traces could be analyzed and fitted by $-\Delta R_t / R = b k_1 n_0 / [(k_2 n_0 + k_1) e^{k_1 t} - k_2 n_0]$ to extract the rate constants k_1 and k_2 . For each sample, the fluctuation of the fitted constants at different pump fluences is slight and therefore the average values from all fluences (2–42 $\mu\text{J cm}^{-2}$) are used for discussion and summarized in Fig. 2.

In LHPs, the first-order decay process observed by transient reflectance/transmittance is usually assigned to Shockley-Reed recombination¹³ or carrier diffusion.³² The former usually occurs on tens to hundreds of nanoseconds,¹³ while all the first-order processes observed in this study are on a tens-of-picosecond time scale; therefore, we tentatively assign the first-order decay process to carrier diffusion. And for the second-order depopulation process, electron–hole recombination is suggested to be the main mechanism as proposed in many previous studies.^{1,13,31,37,38} Thus, k_1 and k_2 obtained here are the photocarrier diffusion and electron–hole recombination rate constants, respectively. As shown in Fig. 2, both have a strong dependence on the crystal structure phase. Specifically, k_1 for three β -phased samples is $\sim 3.6 \times 10^9 \text{ s}^{-1}$, which decreases to $\sim 2.8 \times 10^9 \text{ s}^{-1}$ for two γ -phased ones, with an amplitude reduction of $\sim 20\%$; while k_2 for the β -phased samples is $\sim 1.1 \times 10^{-10} \text{ cm}^3 \text{ s}^{-1}$, which increases to $\sim 1.9 \times 10^{-10} \text{ cm}^3 \text{ s}^{-1}$ for the γ -phased ones, with an amplitude growth of almost 2 times.

It should be noted that the observed different carrier behaviours in these five samples originate from their distinctive intrinsic characters, and the impact from extrinsic factors such as grain size is negligible. Firstly, in TR experiments (detailed in S2, ESI †), the diameters of both the pump and probe light are in the millimetre range, while the film thickness is ~ 200 nm. As a result, only the longitudinal diffusion along the thickness needs to be considered within 1 ns. Since the majority grain size of all samples, 200–800 nm (Fig. S1(c), ESI †), is larger than the thickness, the monitored diffusion process should not be limited by the grain size. Secondly, the observed recombination is a second-order electron–hole recombination, which occurs mainly within the grains and therefore should not be affected by the grain size.

Discussion

In a lead iodide perovskite, the corner-shared PbI₆ octahedrons build up a skeleton or framework with the A-site cations

embedding as the limbs. In the low symmetry tetragonal (β) and orthorhombic (γ) crystalline structures, the PbI₆ octahedrons show different tilted and distorted levels, as sketched in Fig. 3 and summarized in Table 1. Both experimental studies^{18,28,39,40} and theoretical predictions^{19,27,41,42} have suggested that at room temperature the organic–inorganic hybrid MAPbI₃ and FA_{0.9}Cs_{0.1}PbI₃ are in the β phase. The distorted PbI₆ octahedrons are dynamically disordered owing to their anharmonic vibration, and the A-site cations are randomly oriented. Both the distorted PbI₆ octahedrons and A-site cations become ordered in the γ phase as the PbI₆ octahedrons vibrate harmonically and the organic cations orient regularly. In β -CsPbI₃, Cs $^+$ cations are ordered and only the dynamic disorder of the PbI₆ octahedrons is still present, which will disappear when the β to γ phase change occurs.⁸

In the following, we focus firstly on the carrier recombination process. In the past decade, the key factors dominating the carrier dynamics were extensively explored in LHPs, yet majorly in the organic–inorganic hybrid ones.^{1,9,13,39,43–49} For example, the bimolecular recombination rate of MAPbI₃ was observed to be much smaller in the β -phase than in the γ -phase,^{1,43} which was proposed to be assisted by the disordered orientation of the organic cations with the apparent fact that the orientation of the MA $^+$ cation is dynamically disordered in β -MAPbI₃ but ordered in γ -MAPbI₃ (Fig. 3).^{39,44} Following this supposition, the charge separation model,^{9,45} polaron model^{13,46} and others were put forward to explain the underlying physical mechanism. The charge separation model suggested that electrons and holes were separated by the different nanoscale localizations of the conduction and valence band-edges, while the separation efficiency was improved in β -MAPbI₃ by the long-range potential fluctuation created by the randomly oriented dipole moment of the A-site organic cation, MA $^+$.^{9,45} The polaron model proposed that the self-trapped electron (or hole) and the associated atomic displacement formed a polaron,^{13,46} and the random rotation of MA $^+$ in the β phase would assist the formation of the polaron.^{47–49} The direct observation of a faster

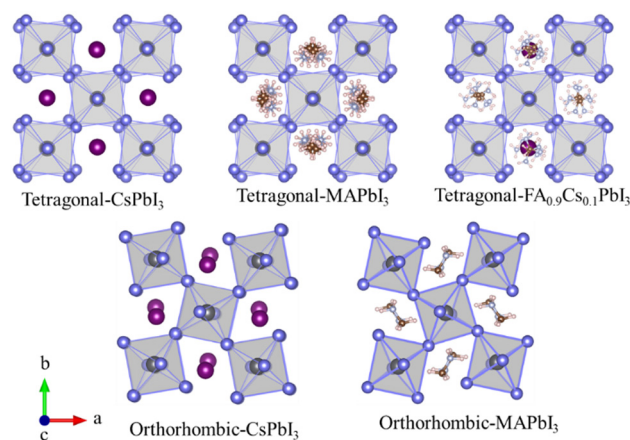


Fig. 3 Sketched dynamic crystal structures for β -phased tetragonal CsPbI₃, MAPbI₃ and FA_{0.9}Cs_{0.1}PbI₃^{18,23,27,28} and γ -phased orthorhombic CsPbI₃ and MAPbI₃^{17,25} perovskites.

polaron formation process in the disordered cubic and tetragonal phases than in the ordered orthorhombic phase by the time-resolved optical Kerr effect technique⁵⁰ further strengthened the belief that the disordered A-site orientation was the major factor retarding the bimolecular recombination in LHPs. In summary, those models only took account of the phase dependent orientation of the A-site cations, and completely ignored the order degree of the Pb-I inorganic sublattice in different phases.

The experimental results provided in this study as k_2 in Fig. 2 do not agree on the above negligence. Instead, the influence induced by the disorder degree of the A-site cation is found to be much weaker than that by the Pb-I sublattice. In this study, the all-inorganic LHP β -CsPbI₃ does not have any organic cation, while the organic-inorganic hybrid LHP β -MAPbI₃ carries the disordered organic cations. The experimental results show that they exhibit a similar bimolecular recombination rate, which hints that the orientation of the A-site cations contributes little to the recombination. However, all recombination rates in the β -phase are significantly diverse from those in the γ -phase (Fig. 2). In the γ -phased perovskites, the Pb-I sublattice becomes regularly ordered, and the bimolecular recombination rate is almost 2 times higher than their twin siblings in the β -phase. Therefore, we propose that the disordered Pb-I sublattice is the essential structural factor dominating the recombination process, which also agrees with some previous theoretical studies based on DFT calculations.^{12,14} Though the charge localization can be induced by both the potential fluctuation created by the randomly oriented dipole moment of the organic cation and the disordered field generated by the anharmonically vibrated Pb-I sublattice, those calculations show that its stabilization is mainly contributed by the latter.^{12,14} We attribute the greatly different recombination rates in the β - and γ -phased LHPs to their diverse orientation of the distorted PbI₆. Since the electron-hole recombination occurs only after the release of charge localization, the stabilized charge localization in the β -phase by mainly the disorderly distorted Pb-I sublattice is unfavorable and therefore retards the recombination process, twice slower than in the γ -phase. As a result, the β -phase may precede the γ -phase in photoconversion by slower recombination.

The dominant influence of the Pb-I sublattice is also presented in the carrier diffusion dynamics as k_1 in Fig. 2. We observed experimentally that within the same phase, either β or γ , the carrier diffusion is neck and neck; yet it is prominently, 20%, faster in the β -phased samples than γ -phased ones. This indicates that the carrier diffusion is mainly assisted by the disorderly orientation of the distorted Pb-I sublattice. This influence could be explained by a modified polaron model below. Its original version^{13,46} was applied to explain the retarded carrier recombination in the disordered β phase as discussed above and here we modified and extended it to carrier mobility described as polaron transport. We propose that the polaron formation and transport benefits from the disordering of distorted PbI₆ instead of A-site organic cations in the original model. A recent experimental study⁵¹ found that

hot carriers diffuse on the hundreds of femtosecond to tens of picoseconds timescale and then slow down consecutively as they cool down. Polarons usually form at a sub-picosecond timescale,⁴⁶ in competition with the hot carrier cooling process.⁵⁰ If polarons establish before the carriers cool down, they will inherit partial excess energy, namely hot polarons. Some experimental investigations^{50,52,53} have already shown that polarons form faster in the disordered phases than in the ordered phases. We suggest that the softness of the Pb-I sublattice in the β -phase is essential to help the formation of the hot polarons and increase their portion in the polaron family. Owing to the higher kinetic energy, the hot polarons will transport faster than the normal polarons.⁴⁶ Hence, a faster carrier diffusion is observed in the β -phased samples than in the γ -phased ones here. In return, a β -phased sample with organic A-site components may advance in photoconversion by such faster diffusion.

Interestingly, strain relaxation was also suggested to assist the improvement of the power conversion efficiency by suppressing defects and reducing nonradiative recombination in some latest studies.^{5,6} The dynamically disordered Pb-X sublattice/A-site in the β -phased LHPs, which is softer than the ordered Pb-X sublattice/A-site in the γ -phased ones, is actually a kind of strain relaxation.¹⁷ Our study also provides a new perspective for the strain effect as the strain relaxation will both assist photocarrier diffusion and retard electron-hole recombination.

Conclusions

Using the ultrafast TR technique, we found that photoinduced carriers recombined almost 2 times slower and diffused 20% faster in the disordered β -phase than in the ordered γ -phase, both promoting the photoconversion, yet with subtle difference within the same phase. These results demonstrate that the carrier dynamics have a significant dependence on the sample phase but trivial on the A-site component. Such phase dependence is contributed majorly by the distortion property of the Pb-X skeleton and insignificantly by the mobility of the A-site cation limbs. We hope that this study may stimulate further theoretical and structural dynamic experimental studies to understand the contribution of the Pb-X sublattice. For example, the influence of PbX₆ distortion on carrier dynamics is worth further investigation, which is pending on the maturation of the fabrication methods for samples in the α phase.

Author contributions

H. Z., J. C. and Y. Z. designed the research; Y. W., T. Z. and Y. C. prepared the samples; H. Z. performed the TR research; H. Z. and J. C. analysed the data and wrote the paper; Y. Z. and J. C. supervised the whole work.

Conflicts of interest

The authors declare no conflict of interest.

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